

512 K (32 K × 16) Static RAM

Features

■ Pin- and function-compatible with CY7C1020CV33

■ Temperature Ranges

□ Commercial: 0 °C to 70 °C
□ Industrial: −40 °C to 85 °C
□ Automotive: −40 °C to 125 °C

■ High speed
□ t_{AA} = 10 ns

■ CMOS for optimum speed/power

■ Low active power □ 325 mW (max)

■ Automatic power-down when deselected

■ Independent control of upper and lower bits

■ Available in Pb-free and non Pb-free 44-pin TSOP II package

Functional Description

The CY7C1020CV33 is a high-performance CMOS static RAM organized as 32,768 words by 16 bits. This device has an automatic power-down feature that significantly reduces power consumption when deselected.

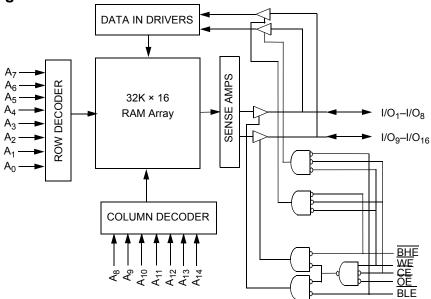
Writing to the device is accomplished by taking Chip Enable (\overline{CE}) and Write Enable (\overline{WE}) inputs LOW. If Byte Low Enable (\overline{BLE}) is LOW, then data from I/O pins $(I/O_1$ through $I/O_8)$, is written into the location specified on the address pins $(A_0$ through $A_{14})$. If Byte High Enable (\overline{BHE}) is LOW, then data from I/O pins $(I/O_9$ through $I/O_{16})$ is written into the location specified on the address pins $(A_0$ through $A_{14})$.

Reading from the device is accomplished by taking Chip Enable $(\overline{\text{CE}})$ and Output Enable $(\overline{\text{OE}})$ LOW while forcing the Write Enable $(\overline{\text{WE}})$ HIGH. If Byte Low Enable $(\overline{\text{BLE}})$ is LOW, then data from the memory location specified by the address pins will appear on I/O₁ to I/O₈. If Byte High Enable $(\overline{\text{BHE}})$ is LOW, then data from memory will appear on I/O₉ to I/O₁₆. See the truth table at the back of this data sheet for a complete description of read and write modes.

The input/output pins (I/O $_1$ through I/O $_{16}$) are placed in a high-impedance state when the device is deselected (\overline{CE} HIGH), the outputs are disabled (\overline{OE} HIGH), the BHE and BLE are disabled (BHE, BLE HIGH), or during a write operation (\overline{CE} LOW, and \overline{WE} LOW).

The CY7C1020CV33 is available in standard 44-pin TSOP Type II package.

Logic Block Diagram



Cypress Semiconductor CorporationDocument Number: 38-05133 Rev. *H

CY7C1020CV33



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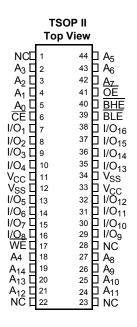
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Selection Guide

		-10	-12	– 15	Unit
Maximum Access Time		10	12	15	ns
Maximum Operating Current	Commercial/Industrial	90	85	80	mA
	Automotive	_	_	85	mA
Maximum CMOS Standby Current	Commercial/Industrial	5	5	5	mA
	Automotive	_	_	10	mA

Pin Configuration [1]



Note

^{1.} NC pins are not connected on the die.



Pin Definitions

Pin Name	TSOP - Pin Number	I/O Type	Description
A ₀ -A ₁₄	5, 4, 3, 2, 18, 44, 43, 42, 27, 26, 25, 24, 21, 20, 19	Input	Address Inputs used to select one of the address locations.
I/O ₁ –I/O ₁₆	7-10, 13-16, 29-32, 35-38	Input/Output	Bidirectional Data I/O lines . Used as input or output lines depending on operation.
NC	1, 22, 23, 28	No Connect	No Connects. Not connected to the die.
WE	17	Input/Control	Write Enable Input, active LOW. When selected LOW, a Write is conducted. When deselected HIGH, a Read is conducted.
CE	6	Input/Control	Chip Enable Input, active LOW. When LOW, selects the chip. When HIGH, deselects the chip.
BHE, BLE	40, 39	Input/Control	Byte Write Select Inputs, active LOW. $\overline{\rm BHE}$ controls I/O ₁₆ –I/O ₉ , $\overline{\rm BLE}$ controls I/O ₈ –I/O ₁ .
ŌĒ	41	Input/Control	Output Enable, active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins are allowed to behave as outputs. When deasserted HIGH, I/O pins are tri-stated, and act as input data pins.
V _{SS}	12, 34	Ground	Ground for the device . Should be connected to ground of the system.
V _{CC}	11, 33	Power Supply	Power Supply inputs to the device.

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Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested. Ambient temperature with power applied –55 °C to +125 °C Supply voltage on V_{CC} to relative $\mbox{GND}^{[2]}....-\mbox{0.5 V}$ to +4.6 V

DC input voltage^[2].....–0.5 V to V_{CC} + 0.5 V

Current into outputs (LOW)	20 mA
Static discharge voltage(per MIL-STD-883, method 3015)	> 2001 V
Latch-up current	> 200 mA

Operating Range

Range	Ambient Temperature	V _{CC}		
Commercial	0 °C to +70 °C	3.3 V \pm 10%		
Industrial	–40 °C to +85 °C	3.3 V ± 10%		
Automotive	–40 °C to +125 °C	3.3 V ± 10%		

Electrical Characteristics

Over the Operating Range

Parameter	Description	Toot Condit	Test Conditions			-12		-15		Unit
Parameter	Description	rest Condit				Min	Max	Min	Max	Unit
V _{OH}	Output HIGH voltage	V_{CC} = Min, I_{OH} = -4.0) mA	2.4	_	2.4	-	2.4	-	V
V_{OL}	Output LOW voltage	V_{CC} = Min, I_{OL} = 8.0	mA	-	0.4	-	0.4	_	0.4	V
V _{IH}	Input HIGH voltage			2.0	$V_{CC} + 0.3$	2.0	$V_{CC} + 0.3$	2.0	$V_{CC} + 0.3$	V
V _{IL}	Input LOW voltage ^[2]			-0.3	0.8	-0.3	0.8	-0.3	0.8	V
I _{IX}	Input leakage current	$GND \leq V_I \leq V_CC$	Commercial/ Industrial	-1	+1	– 1	+1	- 1	+1	μА
			Automotive	-	_	_	-	-20	+20	μА
I _{OZ}	Output leakage current	$GND \le V_l \le V_{CC}$, Output Disabled	Commercial/ Industrial	-1	+1	– 1	+1	- 1	+1	μА
			Automotive	_	_	_	-	-20	+20	μА
I _{CC}	V _{CC} operating supply current	V_{CC} = Max, I_{OUT} = 0 mA,	Commercial/ Industrial	-	90	-	85	-	80	mA
		$f = f_{MAX} = 1/t_{RC}$	Automotive	-	_	_	-	_	85	mA
I _{SB1}	Automatic CE power-down current	$ \frac{\text{Max V}_{CC}, \overline{CE} \ge V_{IH}}{V_{IN} \ge V_{IH} \text{ or } V_{IN} \le V_{IL}, } $	Commercial/ Industrial	-	15	-	15	-	15	mA
	—TTL Inputs	$f = f_{MAX}$	Automotive	_	_	_	-	_	20	mA
I _{SB2}	Automatic CE power-down current	$\frac{\text{Max V}_{\text{CC}},}{\text{CE} \ge \text{V}_{\text{CC}} - 0.3 \text{ V},}$	Commercial/ Industrial	-	5	-	5	-	5	mA
	—CMOS inputs	$V_{IN} \ge V_{CC} - 0.3 \text{ V},$ or $V_{IN} \le 0.3 \text{ V}, f = 0$	Automotive	-	_	-	_	_	10	mA

Capacitance^[3]

Parameter	Description	Test Conditions	Max	Unit
C _{IN}	Input capacitance	$T_A = 25 ^{\circ}\text{C}$, f = 1 MHz, $V_{CC} = 3.3 ^{\circ}\text{V}$	8	pF
C _{OUT}	Output capacitance		8	pF

Thermal Resistance[3]

Parameter	Description	Test Conditions	44-pin TSOP-II	Unit
Θ_{JA}	,	Test conditions follow standard test methods	76.92	°C/W
$\Theta_{\sf JC}$	Thermal resistance Ciunction to Case)	and procedures for measuring thermal impedance, per EIA/JESD51.	15.86	°C/W

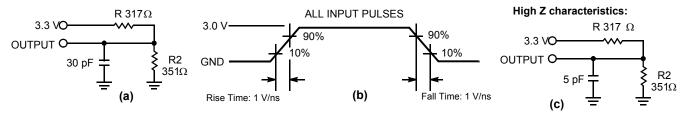
Notes

- V_{IL} (min) = -2.0 V and V_{IH}(max) = V_{CC} + 0.5 V for pulse durations of less than 20 ns.
 Tested initially and after any design or process changes that may affect these parameters.

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AC Test Loads and Waveforms[4]



Switching Characteristics

Over the Operating Range^[4]

Davamatav	Description.	_	10	_	-12		-15	
Parameter	Description	Min	Max	Min	Max	Min	Max	Unit
Read Cycle		<u>'</u>		•	•	•		
t _{RC}	Read cycle time	10	_	12	_	15	_	ns
t _{AA}	Address to data valid	_	10	_	12	_	15	ns
t _{OHA}	Data hold from address change	3	_	3	_	3	_	ns
t _{ACE}	CE LOW to data valid	_	10	_	12	_	15	ns
t _{DOE}	OE LOW to data valid	_	5	_	6	_	7	ns
t _{LZOE}	OE LOW to low Z ^[5]	0	_	0	-	0	_	ns
t _{HZOE}	OE HIGH to high Z ^[5, 6]	_	5	_	6	_	7	ns
t _{LZCE}	CE LOW to low Z ^[5]	3	_	3	_	3	_	ns
t _{HZCE}	CE HIGH to high Z ^[5, 6]	_	5	_	6	_	7	ns
t _{PU} ^[7]	CE LOW to power-up	0	_	0	_	0	_	ns
t _{PD} ^[7]	CE HIGH to power-down	_	10	_	12	_	15	ns
t _{DBE}	Byte enable to data valid	_	5	_	6	_	7	ns
t _{LZBE}	Byte enable to low Z	0	_	0	_	0	_	ns
t _{HZBE}	Byte disable to high Z	_	5	_	6	_	7	ns
Write Cycle ^[8]		•	•	•	•	•	•	•
t _{WC}	Write cycle time	10	_	12	_	15	_	ns
t _{SCE}	CE LOW to write end	8	_	9	_	10	_	ns
t _{AW}	Address set-up to write end	7	_	8	_	10	_	ns
t _{HA}	Address hold from write end	0	_	0	_	0	_	ns
t _{SA}	Address set-up to write start	0	_	0	_	0	_	ns
t _{PWE}	WE pulse width	7	_	8	-	10	_	ns
t _{SD}	Data set-up to write end	5	_	6	_	8	_	ns
t _{HD}	Data hold from write end	0	_	0	_	0	_	ns
t _{LZWE}	WE HIGH to low Z ^[5]	3	_	3	_	3	_	ns
t _{HZWE}	WE LOW to high Z ^[5, 6]	_	5	_	6	_	7	ns
t _{BW}	Byte enable to end of write	7	_	8	_	9	_	ns

Notes

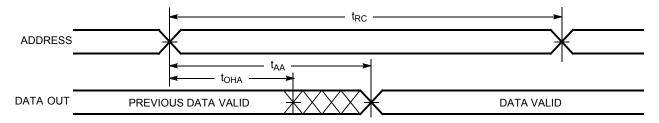
- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.
 At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} is less than t_{LZCE} for any given device.
 t_{HZOE}, t_{HZDE}, t_{HZCE}, and t_{HZWE} are specified with a load capacitance of 5 pF as in part (c) of AC Test Loads. Transition is measured ± 500 mV from steady-state voltage.
 This parameter is guaranteed by design and is not tested.
 The internal Write time of the memory is defined by the overlap of CE LOW, WE LOW and BHE/BLE LOW. CE, WE and BHE/BLE must be LOW to initiate a Write, and the transition of these signals can terminate the Write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the Write.

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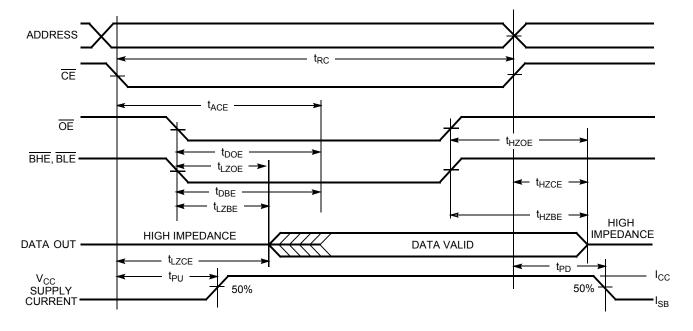


Switching Waveforms

Read Cycle No. 1^[9, 10]



Read Cycle No. 2 (OE Controlled)[10, 11]



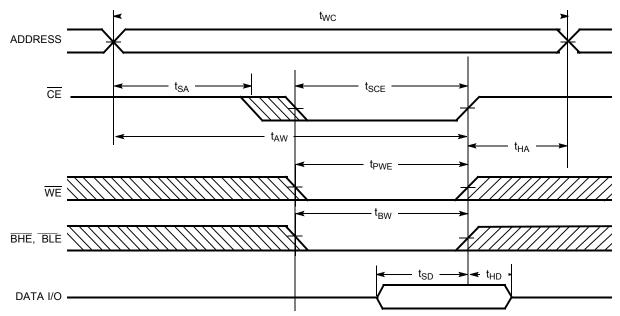
^{9.} Device is continuously selected. OE, CE, BHE and/or BHE = V_{IL}.
10. WE is HIGH for Read cycle.

^{11.} Address valid prior to or coincident with $\overline{\text{CE}}$ transition LOW.

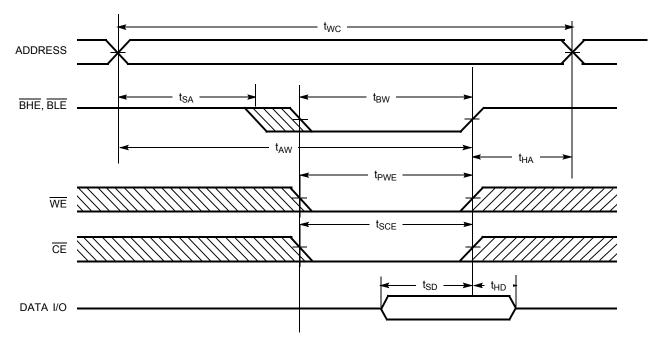


Switching Waveforms (continued)

Write Cycle No. 1 (CE Controlled)[12, 13]



Write Cycle No. 2 (BLE or BHE Controlled)



Notes

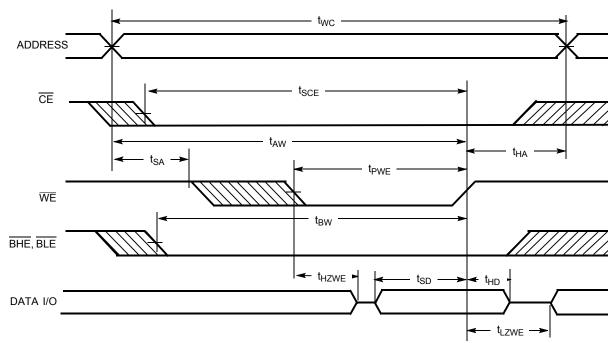
12. Data I/O is high impedance if \overline{OE} or \overline{BHE} and/or $\overline{BLE} = V_{IH}$.

13. If \overline{CE} goes HIGH simultaneously with WE going HIGH, the output remains in a high-impedance state.



Switching Waveforms (continued)

Write Cycle No. 3 (WE Controlled, OE LOW)



Truth Table

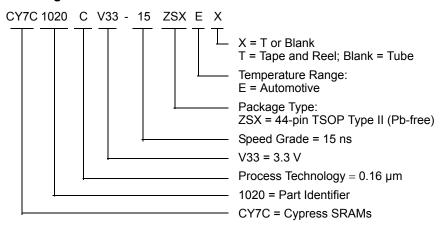
CE	OE	WE	BLE	BHE	I/O ₁ –I/O ₈	I/O ₉ –I/O ₁₆	Mode	Power
Н	Х	Х	Х	Х	High Z	High Z	Power-down	Standby (I _{SB})
L	L	Н	L	L	Data out	Data out	Read—All bits	Active (I _{CC})
			L	Н	Data out	High Z	Read—Lower bits only	Active (I _{CC})
			Н	L	High Z	Data out	Read—Upper bits only	Active (I _{CC})
L	Х	L	L	L	Data in	Data in	Data in Write—All bits	
			L	Н	Data in	High Z	High Z Write—Lower bits only	
			Н	L	High Z	Data in	Write—Upper bits only	Active (I _{CC})
L	Н	Н	Х	Х	High Z	High Z	High Z Selected, outputs disabled A	
L	Х	Χ	Н	Н	High Z	High Z	High Z Selected, outputs disabled Active (I _C	



Ordering Information

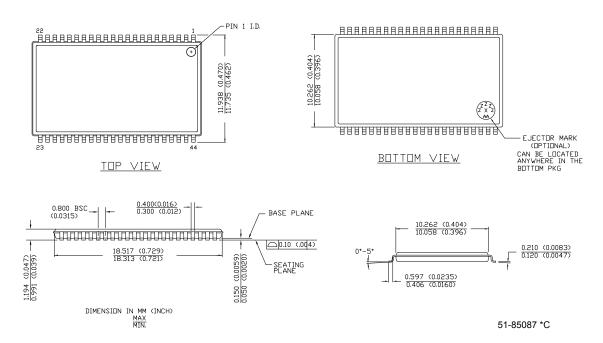
Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
15	CY7C1020CV33-15ZSXE	51-85087	44-pin TSOP Type II (Pb-free)	Automotive
	CY7C1020CV33-15ZSXET	51-85087	44-pin TSOP Type II (Pb-free)	Automotive

Ordering Code Definitions



Package Diagrams

Figure 1. 44-pin TSOP II, 51-85087



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Acronyms

Acronym	Description			
CMOS	complementary metal oxide semiconductor			
CE	chip enable			
I/O	input/output			
OE	output enable			
SRAM	static random access memory			
TSOP	thin small-outline package			
TTL	transistor-transistor logic			
WE	write enable			

Document Conventions

Units of Measure

Symbol	Unit of Measure		
ns	nano seconds		
V	Volts		
μΑ	micro Amperes		
mA	milli Amperes		
mW	milli Watts		
MHz	Mega Hertz		
pF	pico Farad		
°C	degree Celcius		
W	Watts		
%	percent		



Document History Page

Oocument Title: CY7C1020CV33 512 K (32 K × 16) Static RAM Oocument Number: 38-05133						
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change		
**	109428	12/16/01	HGK	New Data Sheet		
*A	115045	05/30/02	HGK	I _{CC} and I _{SB1} data modified		
*B	117615	08/14/02	DFP	Pin 1= NC Pin 18 = A4; remove SOJ package option; remove 8ns option.		
*C	262949	See ECN	RKF	Added Automotive Specs to Data sheet		
*D	334398	See ECN	SYT	Added Lead-Free Product Information		
*E	493543	See ECN	NXR	Added note #1 on page #1 Changed the description of I _{IX} from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Removed I _{OS} parameter from DC Electrical Characteristics table Updated Ordering Information Table		
*F	2897691	03/23/2010	RAME	Updated Ordering Information Updated Package Diagram		
*G	3057593	10/13/2010	PRAS	Updated Ordering Information and added Ordering Code Definitions.		
*H	3100106	12/02/2010	PRAS	Added Acronyms and Units of Measure. Minor edits and updated in new template.		

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